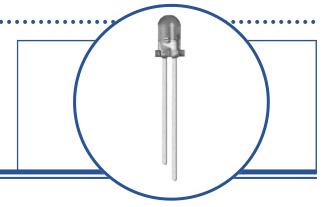
Vertical Cavity Surface Emitting Laser in T-1 Package



OPV332

- 850nm VCSEL technology
- High thermal stability
- Low drive current
- High output power
- Narrow Beam Angle

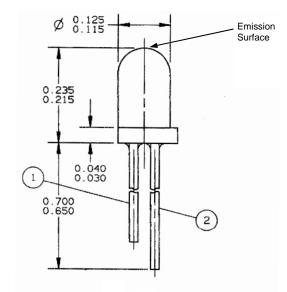


The OPV332 is a Vertical Cavity Surface Emitting Laser (VCSEL) packaged in a dome lens T-1 package. VCSELs offer many advantages in sensing applications when compared to infrared LEDs. These devices require substantially lower drive currents to obtain the same amount of output power as LEDs. This feature allows VCSELs to be used in low power consumption applications such as battery operated equipment.

The dome lens packaging creates a narrow 4 degree beam angle from the device. Long distance applications may benefit from this feature as secondary optics may be eliminated, reducing total system cost. The OPV332 is optically and spectrally compatible with Optek's standard detector products such as the OP500 series phototransistors, OP530 series photodarlingtons and the OP900 series photodiodes.

Applications

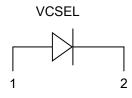
- Non-contact position sensing
- Photoelectric sensors
- Optical encoders
- Light curtains

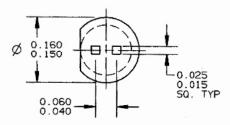




Additional laser safety information can be found on the Optek website. See application bulletin #221.

Classification is not marked on the device due to space limitations. See package outline for centerline of optical radiance. Operating devices beyond maximum rating may result in hazardous radiation exposure.







Optek

Optek reserves the right to make changes at any time in order to improve design and to supply the best product possible.

VCSEL in T-1 Package **OPV332**



Absolute Maximum Ratings

T_A = 25° C unless otherwise noted

Storage Temperature Range	-40° to +100° C
Operating Temperature Range	-40° to +85° C
Lead Soldering Temperature [1/16 inch (1.6mm) from case for 5 sec with soldering iron]	260° C ⁽¹⁾
Maximum Forward Peak Current	20 mA
Maximum Reverse Voltage	5 V

Electrical Characteristics (T_A = 25°C unless otherwise noted)

SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	CONDITIONS
P _{OT}	Total Power Out	1.5			mW	I _F = 7 mA
I _{TH}	Threshold Current			3.0	mA	Note 2
V_{F}	Forward Voltage			2.2	V	I _F = 7 mA
I _R	Reverse Current			100	nA	V _R = 5 V
Rs	Series Resistance	20		55	ohms	Note 3
η	Slope Efficiency	0.28			mW/mA	Note 4
λ	Wavelength	830		860	nm	
Δλ	Optical Bandwidth		0.85		nm	
θ	Beam Divergence		4		Degrees	
$\Delta\eta/\Delta T$	Temp Coefficient of Slope Efficiency		-0.50		%/°C	(0° - 70°C), Note 4
Δλ/ΔΤ	Temp Coefficient of Wavelength		0.06		nm/°C	(0° - 70°C)
$\Delta I_{TH}/\Delta T$	Temp Coefficient of Threshold Current		±1.0		mA	(0° - 70°C), Note 2
$\Delta V_F/\Delta T$	Temp Coefficient for Forward Voltage		-2.5		mV/°C	(0° - 70°C)

NOTES:

- EO.

 RMA flux is recommended. Solder dwell time can be increased to 10 seconds when flow soldering.

 Threshold Current is based on the two line intersection method specified in Telcordia GR-468-Core. Line 1 from 4 mA to 6 mA. Line 2 from 0 mA to 0.5 mA.
- Series Resistance is the slope of the Voltage-Current line from 5 to 8 mA.

 Slope efficiency, is the slope of the best fit LI line from 5 mA to 8 mA with 0.25mA test intervals.

